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N-Channel PowerTrench[®] MOSFET 30 V, 8 m Ω

Features

- Max $r_{DS(on)} = 8 \text{ m}\Omega \text{ at } V_{GS} = 10 \text{ V}, I_D = 13 \text{ A}$
- Max $r_{DS(on)} = 14 \text{ m}\Omega \text{ at } V_{GS} = 4.5 \text{ V}, I_D = 10 \text{ A}$
- Advanced Package and Silicon combination for low r_{DS(on)} and high efficiency
- Next generation enhanced body diode technology, engineered for soft recovery.
- MSL1 robust package design
- 100% UIL tested
- RoHS Compliant

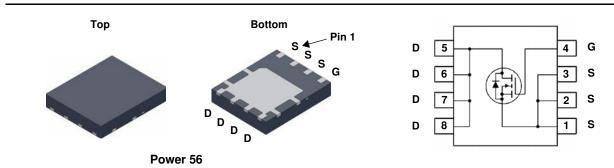


General Description

This N-Channel MOSFET has been designed specifically to improve the overall efficiency and to minimize switch node ringing of DC/DC converters using either synchronous or conventional switching PWM controllers. It has been optimized for low gate charge, low $r_{DS(on)}$, fast switching speed and body diode reverse recovery performance.

Applications

- IMVP Vcore Switching for Notebook
- VRM Vcore Switching for Desktop and Server
- OringFET / Load Switch
- DC-DC Conversion



MOSFET Maximum Ratings T_A = 25 °C unless otherwise noted

Symbol	Parameter			Ratings	Units		
V _{DS}	Drain to Source Voltage			30	V		
V _{GS}	Gate to Source Voltage			±20	V		
ID	Drain Current -Continuous (Package limited)	T _C = 25 °C		28			
	-Continuous (Silicon limited)	T _C = 25 °C		45			
	-Continuous	T _A = 25 °C	(Note 1a)	13.5	A		
	-Pulsed			50			
E _{AS}	Single Pulse Avalanche Energy		(Note 3)	21	mJ		
P _D	Power Dissipation	T _C = 25 °C		27	- w		
	Power Dissipation	T _A = 25 °C	(Note 1a)	2.5			
T _J , T _{STG}	Operating and Storage Junction Temperature Range			-55 to +150	°C		

Thermal Characteristics

$R_{ ext{ heta}JC}$	Thermal Resistance, Junction to Case	4.6	°C/W
$R_{ extsf{ heta}JA}$	Thermal Resistance, Junction to Ambient (Note 1	a) 50	C/ VV

Package Marking and Ordering Information

Device Marking	Device	Package	Reel Size	Tape Width	Quantity
FDMS7692A	FDMS7692A	Power 56	13 "	12 mm	3000 units

Electrical Characteristics T _J = 25 °C unless otherwise noted								
Symbol	Parameter	Test Conditions	Min	Тур	Max	Units		
Off Chara	cteristics							
BV _{DSS}	Drain to Source Breakdown Voltage	$I_{D} = 250 \ \mu A, \ V_{GS} = 0 \ V$	30			V		
ΔBV _{DSS} ΔTJ	Breakdown Voltage Temperature Coefficient	$I_D = 250 \ \mu\text{A}$, referenced to 25 °C		13		mV/°C		
I _{DSS}	Zero Gate Voltage Drain Current	$V_{DS} = 24 V, V_{GS} = 0 V$			1	μA		
I _{GSS}	Gate to Source Leakage Current, Forward	$V_{GS} = 20 V, V_{DS} = 0 V$			100	nA		
On Chara	cteristics							
V _{GS(th)}	Gate to Source Threshold Voltage	$V_{GS} = V_{DS}, I_{D} = 250 \ \mu A$	1.0	2.0	3.0	V		
$\frac{\Delta V_{GS(th)}}{\Delta T_J}$	Gate to Source Threshold Voltage Temperature Coefficient	$I_D = 250 \ \mu$ A, referenced to 25 °C		-6		mV/°C		
	Static Drain to Source On Resistance	V _{GS} = 10 V, I _D = 13 A		6.8	8			
r _{DS(on)}		$V_{GS} = 4.5 \text{ V}, \text{ I}_{D} = 10 \text{ A}$		10	14	mΩ		
		V _{GS} = 10 V, I _D = 13 A, T _J = 125 °C		9.5	12			
9fs	Forward Transconductance	V _{DS} = 5 V, I _D = 13 A		68		S		
Dynamic	Characteristics							
C _{iss}	Input Capacitance	V 45.V.V. 6.V.		1015	1350	pF		
C _{oss}	Output Capacitance	V _{DS} = 15 V, V _{GS} = 0 V, f = 1 MHz		325	435	pF		
C _{rss}	Reverse Transfer Capacitance			45	65	pF		
R _g	Gate Resistance			1.5	3.0	Ω		
Switching	g Characteristics							
t _{d(on)}	Turn-On Delay Time			8	16	ns		
t _r	Rise Time	V _{DD} = 15 V, I _D = 13 A,		2.7	10	ns		
t _{d(off)}	Turn-Off Delay Time	$V_{GS} = 10 \text{ V}, \text{ R}_{GEN} = 6 \Omega$		17	31	ns		
t _f	Fall Time			2.3	10	ns		
Qg	Total Gate Charge	V _{GS} = 0 V to 10 V		15	22	nC		
Qg	Total Gate Charge	$V_{GS} = 0$ V to 4.5 V $V_{DD} = 15$ V,		7	10	nC		
Q _{gs}	Gate to Source Charge	I _D = 13 A		3.4		nC		
Q _{gd}	Gate to Drain "Miller" Charge			1.9		nC		
Drain-Soເ	urce Diode Characteristics							
V _{SD}	Source to Drain Diode Forward Voltage	$V_{GS} = 0 V, I_S = 2.1 A$ (Note 2)		0.75	1.1	v		
		$V_{GS} = 0 V, I_S = 13 A$ (Note 2)		0.84	1.2			
t _{rr}	Reverse Recovery Time	- I _F = 13 A, di/dt = 100 A/μs		21	34	ns		
Q _{rr}	Reverse Recovery Charge			6	12	nC		
t _{rr}	Reverse Recovery Time	- I _F = 13 A, di/dt = 300 A/μs		17	31	ns		
Q _{rr}	Reverse Recovery Charge	•		12	21	nC		



2. Pulse Test: Pulse Width < 300 $\mu s,$ Duty cycle < 2.0%.

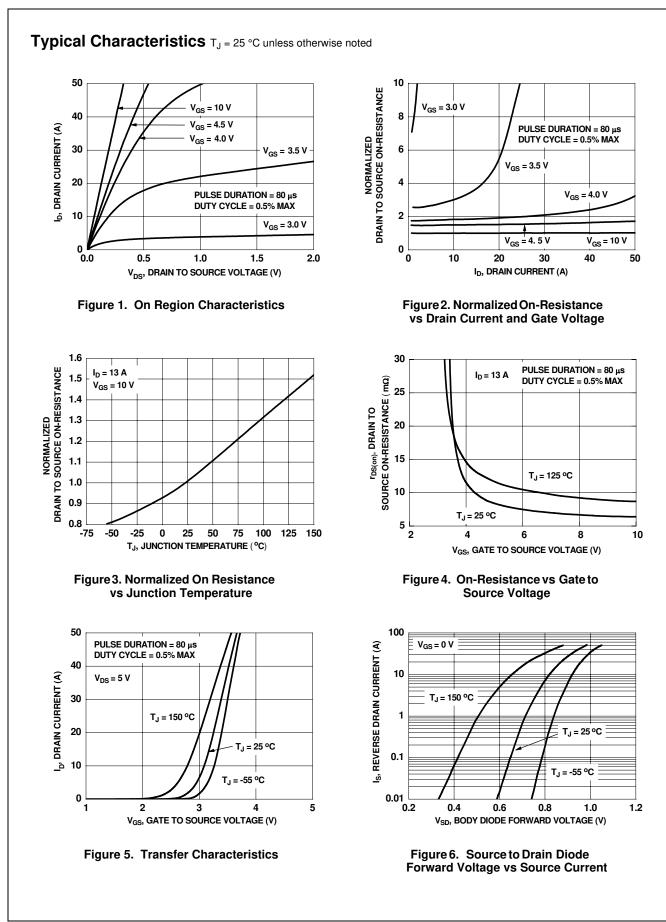
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3. Starting T_J = 25 °C, L = 0.3 mH, I_{AS} = 12 A, V_{DD} = 27 V, V_{GS} = 10 V.

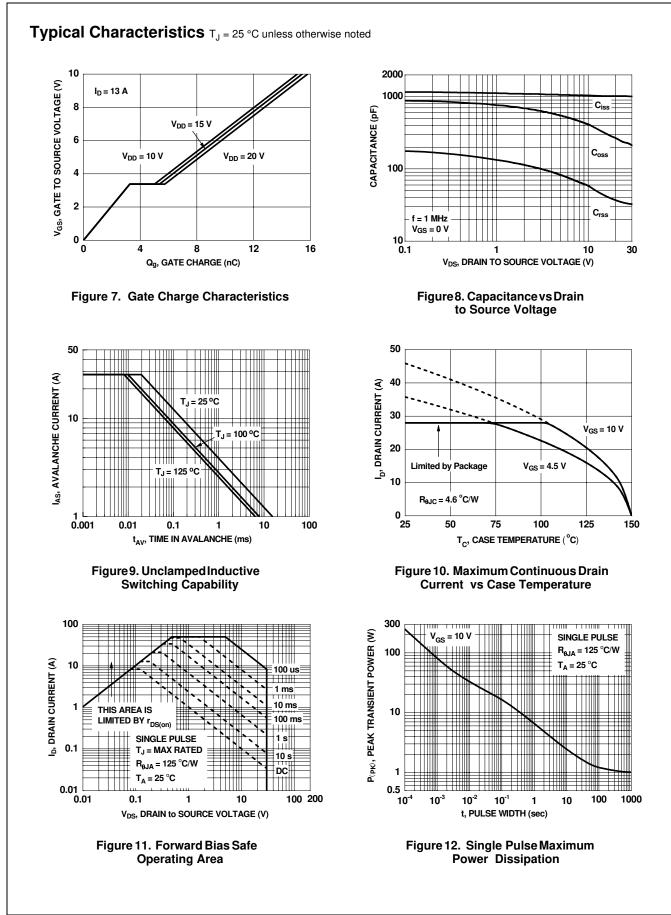
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a. 50 °C/W when mounted on a 1 in^2 pad of 2 oz copper.

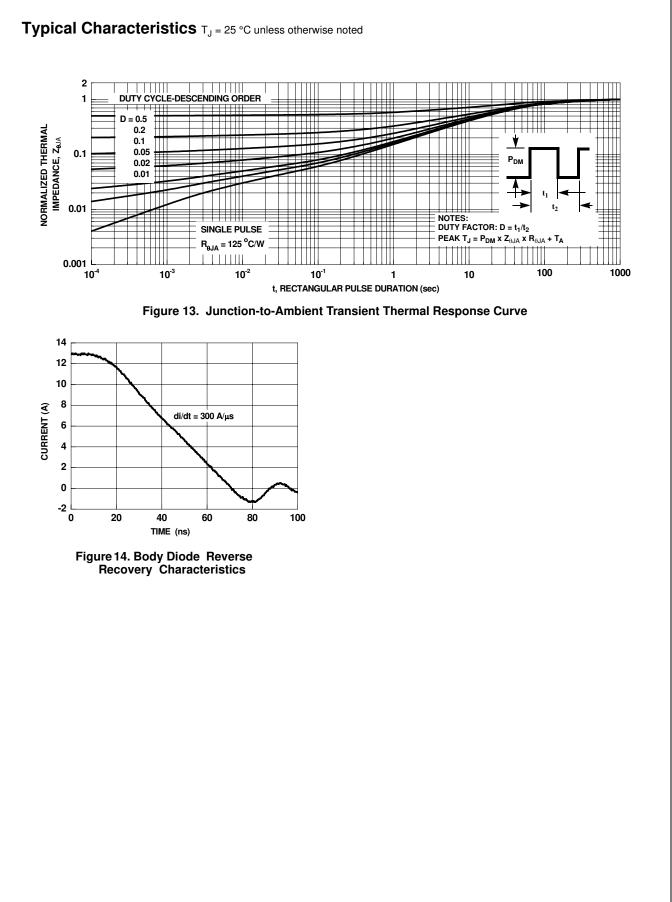
b. 125 °C/W when mounted on a minimum pad of 2 oz copper.

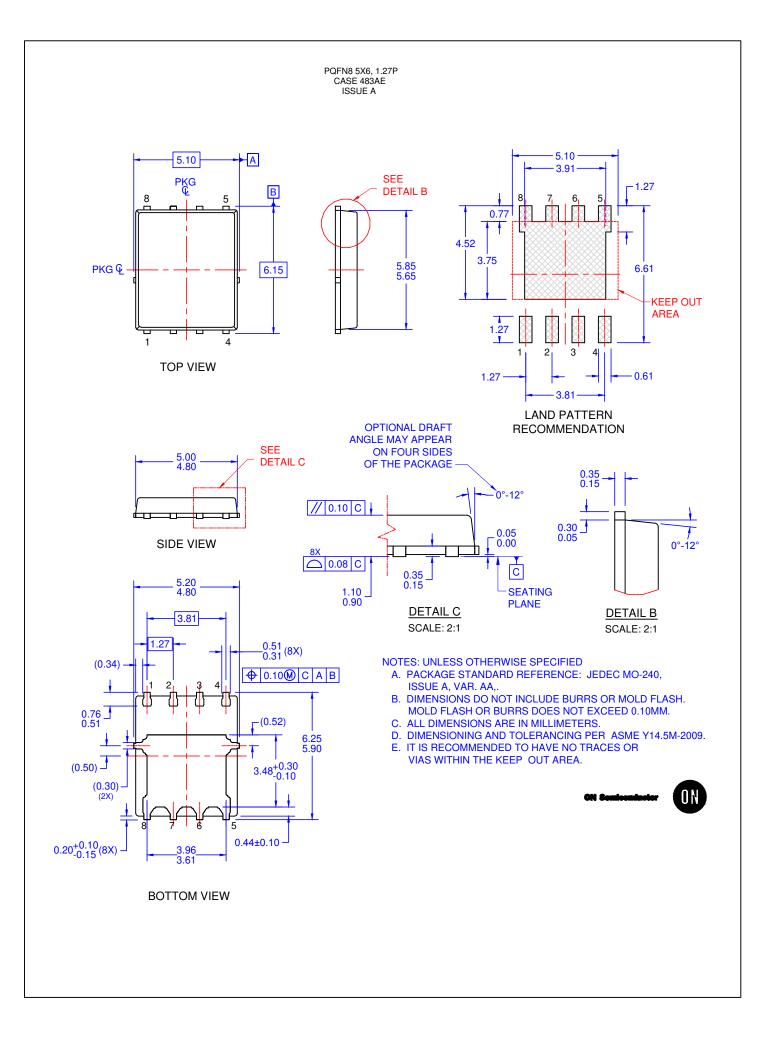






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